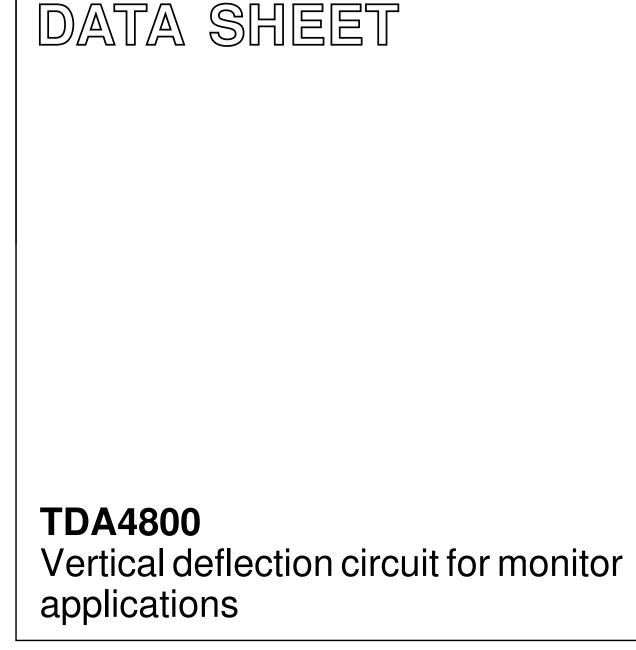
INTEGRATED CIRCUITS



Product specification Supersedes data of February 1992 File under Integrated Circuits, IC02 1997 Mar 27



TDA4800

FEATURES

- Fully integrated, few external components
- RC oscillator with wide sync range of 1 : 3 (e.g. 50 to 150 Hz)
- Synchronization by positive or negative going sync pulse
- · Blanking pulse duration is determined externally
- Dual frequency criterion for automatic amplitude switch-over (e.g. 50 to 60 Hz)
- Guard circuit for screen protection
- Sawtooth generator with buffer stage supplied by external voltage
- Preamplifier
- Power output stage with thermal and SOAR protection
- Flyback generator
- Internal voltage stabilizer.

QUICK REFERENCE DATA

GENERAL DESCRIPTION

The TDA4800 is an integrated circuit for vertical deflection primarily in monitors (and TV receivers). The complete circuit consists of 11 main functional blocks as shown in Fig.1.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{P1}	supply voltage (pin 6)		10	-	30	V
V _{P2}	supply voltage (pin 10)		10	-	45	V
Ι _Ρ	supply current (pins 6 and 10)	note 1	-	215	-	mA
I _{7(p-p)}	output current (peak-to-peak value)		_	_	2.6	A
f _{sync}	picture frequency	notes 1 and 2	-	-	135	Hz
V ₃	positive sync input pulse		1.0	-	6.0	V
V ₃	negative sync input pulse		-0.5	-	-0.7	V
T _{amb}	operating ambient temperature	note 3	-20	_	+70	°C

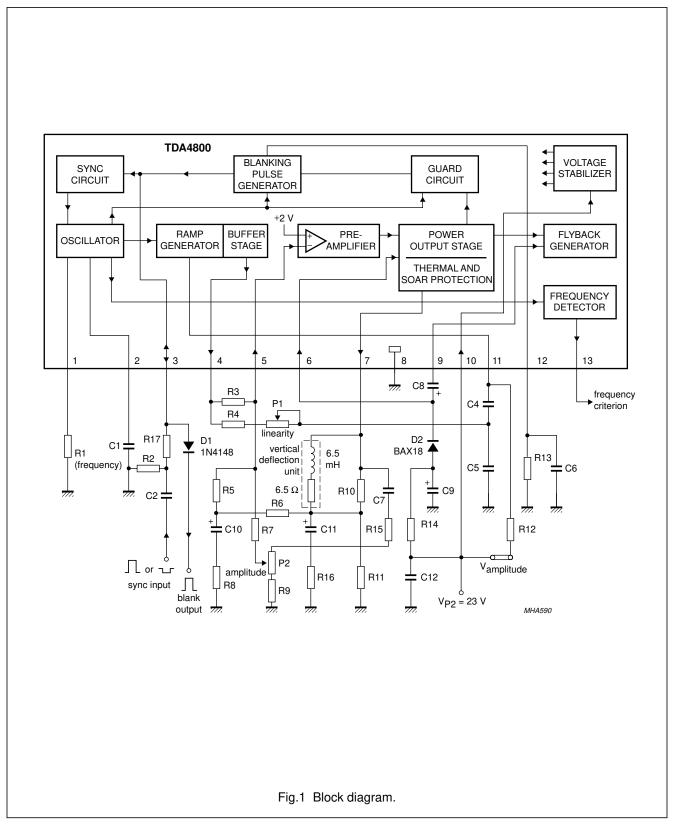
Notes

- 1. Measured in Fig.4.
- 2. $f_o = 45 \text{ Hz} (f_{sync(max)} = 3f_o).$
- 3. $P_{tot} = 3.6 \text{ W}$ for $R_{th(j-a)} = 20 \text{ K/W}$.

ORDERING INFORMATION

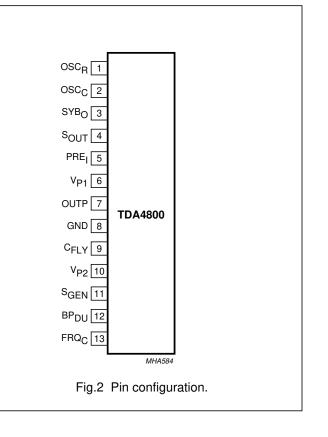
TYPE		PACKAGE				
NUMBER	NAME	DESCRIPTION	VERSION			
TDA4800	DBS13P	plastic DIL-bent-SIL power package; 13 leads (lead length 12 mm)	SOT141-6			

BLOCK DIAGRAM



PINNING

SYMBOL	PIN	DESCRIPTION
OSC _R	1	oscillator resistor
OSC _C	2	oscillator capacitor
SYBO	3	sync input; blanking pulse output
S _{OUT}	4	sawtooth output
PRE	5	preamplifier input
V _{P1}	6	supply voltage 1
OUTP	7	deflection output
GND	8	ground
C _{FLY}	9	pin for the flyback generator capacitor
V _{P2}	10	supply voltage 2
S _{GEN}	11	sawtooth generator
BP _{DU}	12	blanking pulse duration
FRQ _C	13	frequency criterion



FUNCTIONAL DESCRIPTION

The complete circuit consists of the following functional blocks as shown in Fig.1:

- 1. Oscillator
- 2. Synchronization circuit
- 3. Blanking pulse generator
- 4. Frequency detector and storage
- 5. Ramp generator
- 6. Buffer stage
- 7. Preamplifier
- 8. Power output stage
- 9. Flyback generator
- 10. Guard circuit
- 11. Voltage stabilizer.

Oscillator (pins 1 and 2)

The oscillator is an RC-oscillator with a threshold value switch, which ensures very good frequency stability.

The upper and lower threshold voltages are defined by an internal voltage divider.

An external capacitor C1 at pin 2 is charged by a constant current source. When the scan voltage of C1 reaches the upper threshold voltage, oscillator flyback starts. Capacitor C1 discharges via an internal resistor and transistor until the lower threshold is reached.

The constant charge current and free-running frequency f_o are adjusted by an external resistor R1 at pin 1:

$$f_o = \frac{1}{K \times R1 \times C1}$$
 with K = 0.68.

Synchronization circuit (pin 3)

A positive- or negative-going pulse fed to pin 3 synchronizes the oscillator by lowering the upper threshold voltage. The synchronizing range is f_o to $3f_o$. For example: $f_o = 50 \text{ Hz} \rightarrow f_{\text{sync}(\text{max})} = 150 \text{ Hz}.$

Blanking pulse generator (pin 3)

Also at pin 3 a blanking pulse is available. Diode D1 separates the synchronization pulse from the blanking pulse. During scanning, the external capacitor C6 at pin 12 is charged to an internal stabilized voltage V_{stab2} . The blanking pulse starts with the beginning of oscillator flyback; then capacitor C6 discharges via the external resistor R13 at pin 12. The blanking pulse stops when the capacitor voltage is $\frac{1}{2}V_{stab2}$.

The blanking pulse duration is determined by the values of external components R13 and C6 at pin 12: $t_{bl} = R13 \times C6 \times Ln2.$

Frequency detector with storage (pin 13)

At the end of the scanning period a frequency detector detects the oscillator frequency (see "Note" below).

When this frequency is above the threshold a flip-flop is set to store this information. The output is an open collector output.

NOTE

Frequency detector change-over at pin 13 from low (= low frequency) to high (= high frequency) is determined by f_0 : $f_{threshold} = 1.23 \times f_0$.

Ramp generator (pin 11)

The ramp generator consists of two external series capacitors C4 and C5, external charge resistor R12 (connected to pin 11), and an internal differential amplifier which is synchronously switched by the oscillator.

External capacitors C4 and C5 at pin 11 are charged by the charging current via the external charge resistor R12 until oscillator flyback starts. C4 and C5 are then discharged via pin 11 by an internal resistor and transistor. This generates a positive-going ramp voltage.

Buffer stage (pin 4)

The buffer stage consists of two emitter followers. The ramp voltage is fed via the buffer stage and is available at pin 4 with a low ohmic output impedance. With R4 and P1 it generates a ramp function, which, together with the feedback network of the deflection yoke, gives a high degree of linearity at the picture tube. The linearity can be adjusted by P1.

Preamplifier (pin 5)

The preamplifier is a differential amplifier. The non-inverting input is fixed at about 2 V by an internal voltage divider. The inverting input at pin 5 is connected to the ramp voltage via R3 and feedback network P2, R5 to R11, R15, R16, C7, C10 and C11.

Power output stage (pin 7)

The power output stage is an amplifier with a quasi-complementary class-B output. The output is connected to pin 7.

The power stage includes SOAR and thermal protection.

Flyback generator (pin 9)

The flyback generator has an external capacitor C8 at pin 9. During scanning, the internal circuit switches pin 9 almost to ground; thereby C8 is charged by the supply voltage via external components R14 and D2.

During the flyback time pin 9 is switched almost to the supply voltage, so that the supply voltage for the power output stage (pin 6) is nearly doubled. This high flyback voltage ensures a very short flyback time.

Guard circuit (pin 3)

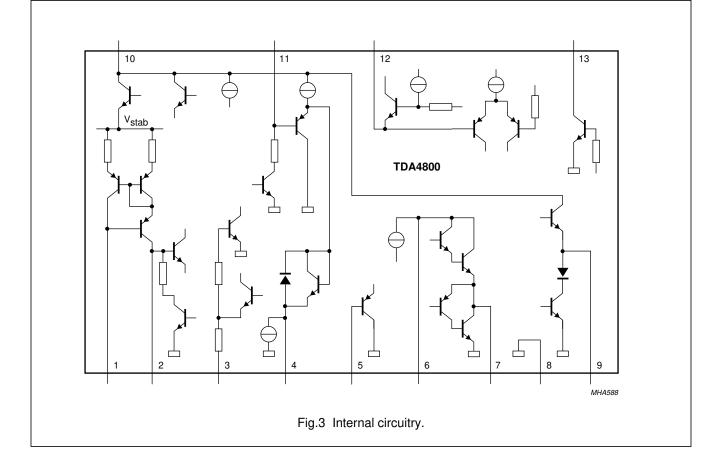
When the vertical deflection current is absent (e.g. short-circuited, or open-circuited of the yoke) the guard circuit changes the blanking pulse at pin 3 into a DC signal which blanks the beam current to protect the screen.

Also an oscillator defect (C1 short-circuited or R1 disconnected from pin 1) switches on the guard circuit.

INTERNAL CIRCUITRY



The voltage stabilizer circuit provides a stable operating voltage of about 7.5 V for several internal circuits of the TDA4800.



LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 134).

SYMBOL	PARAMETER	CONDITIONS	MIN.	MAX.	UNIT
V ₂	voltages		0	6	V
V ₁₁			0	24	V
V ₁₂			0	6	V
V ₁₃			0	50	V
V ₁₀	supply voltages (V _P)		0	50	V
V ₉			0	50	V
V ₇			0	60	V
V ₆			0	60	V
V ₅			0	6	V
V ₄			0	24	V
V ₃			-0.7	+6	V
l ₁	currents		0	-1	mA
l ₃			+3	-10	mA
I ₄			0	-5	mA
I ₆ , I ₇ , I ₈			nc	ote 1	
lg			-1.5	+1.5	A
I ₁₁			-0.1	+30	mA
T _{stg}	storage temperature		-25	+150	°C
T _{amb}	operating ambient temperature	note 2	-20	+70	°C
Tj	junction temperature	note 3	-	150	°C
P _{tot}	total power dissipation	note 2	-	-	W
V _{ESD}	ESD sensitivity	note 4	-2000	+2000	V

Notes

- 1. I₆, I₇ and I₈ are limited by SOAR protection circuit that ensures that short-circuiting between the output pin 7 and supply voltage or ground does not destroy the output stage. A short-circuit may be soldered into the printed-circuit board or may sometimes (non-periodically) occur in the applied circuit.
- 2. The maximum value for the operating ambient temperature range and the power dissipation depends on the heatsink.
- 3. Internally limited by thermal protection: switching temperature point at $T_j = 150 \pm 8$ °C.
- 4. Human body model: $1.5 \text{ k}\Omega$, 100 pF, 5 pulses.

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	VALUE	UNIT
R _{th(j-a)}	thermal resistance from junction to ambient	20	K/W
R _{th(j-mb)}	thermal resistance from junction to mounting base	5	K/W

1997 Mar 27

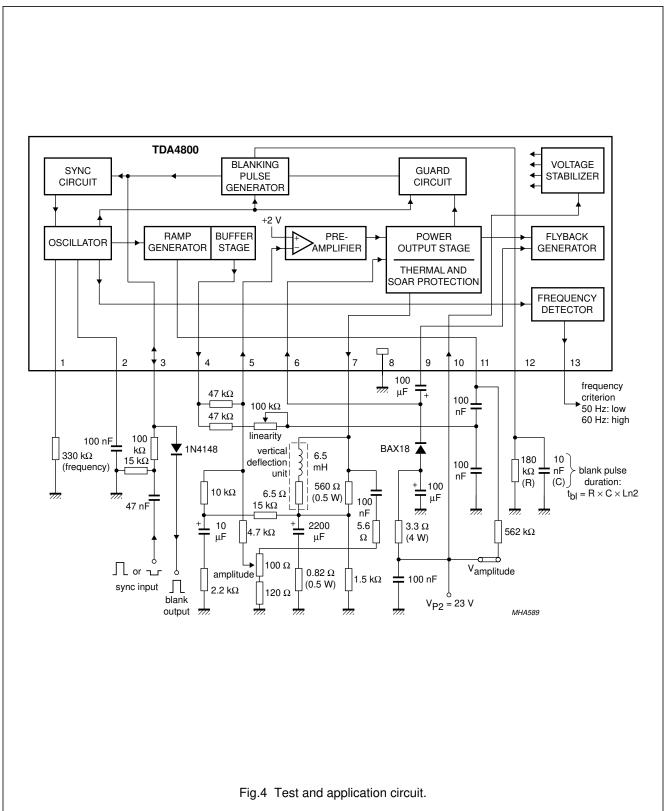
CHARACTERISTICS All voltages are measured to GND (ground; pin 8); $T_{amb} = 25 \text{ °C}$; $V_P = 23 \text{ V}$; unless otherwise specified.

SYMBOL	PARAMETER	CONDITIONS	MIN.	TYP.	MAX.	UNIT
V _{P1}	supply voltage (pin 6)		10	-	30	V
V _{P2}	supply voltage (pin 10)		10	_	45	V
I ₁₀	supply current	$V_{10} = 25 \text{ V}; V_5 = 3 \text{ V}$ without load	-	12	_	mA
I ₆	supply current	$V_6 = 25 V; V_5 = 1 V$ without load	-	20	_	mA
I ₆	supply current	$V_6 = 25 V; V_5 = 3 V$ without load	-	5	_	mA
V _{7(min)}	minimum output voltage	I ₇ = 1 A	-	1.4	1.65	V
V _{7(max)}	maximum output voltage	$I_7 = -1 A$	$V_{6} - 2.3$	$V_{6} - 2.0$	-	V
V ₉	output voltage during flyback	l ₉ = −1 A	-	$V_{10} - 2.2$	_	V
I ₇	output current		-	-	±1.3	А
l ₉	output current		-	-	±1.3	А
I ₅	preamplifier input current		-	-0.1	_	μA
V ₁	stabilized voltage		6.1	6.8	7.3	V
V ₃	blanking pulse output voltage		-	5.7	-	V
R ₃	blanking pulse output resistance		-	300	_	Ω
l ₃	blanking pulse output current		0	_	-3	mA
t _{bl}	blanking pulse duration	R = 100 kΩ; C = 10 nF (pin 12)	640	680	730	μs
V ₁₁	output voltage ramp generator		0.3	_	20	V
I ₁₁	output current ramp generator		-2	-	$15 imes 10^3$	μA
V ₁₃	output voltage frequency detector	lower frequency I ₁₃ = 1 mA	-	_	1.0	V
I ₁₃	leakage current frequency detector	higher frequency $V_{13} = 50 \text{ V}$	-	_	1.0	μA
V ₄	output voltage buffer stage		0	_	20	V
I ₄	output current buffer stage		-	-	-4.0	mA
V ₃	synchronizing input voltage	positive sync	1.0	-	6.0	V
V ₃	synchronizing input voltage	negative sync	-0.5	-	-0.7	V
	tolerance of free running oscillator	without sync	-3.0	-	+3.0	%
$\frac{\Delta f}{f} \times \frac{1}{\Delta T_{mb}}$	oscillator temperature dependency	T _{mb} = 20 to 100 °C	-	10 ⁻⁴	-	K ⁻¹
$\frac{\Delta f}{f} \times \frac{1}{\Delta V_{P}}$	oscillator voltage dependency	V _P = 10 to 30 V	-	4 × 10 ⁻⁴	-	K-1
$rac{f_o}{f_{sync}}$	synchronizing ratio		1 : 2.9	1:3	_	

applications

Philips Semiconductors

TEST AND APPLICATION INFORMATION



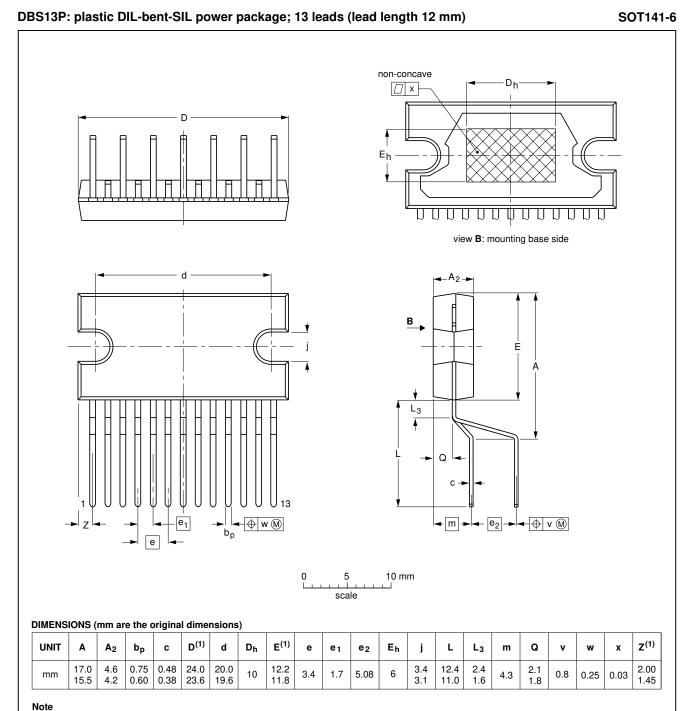
Product specification

TDA4800

TDA4800 in the test and application circuit (see Fig.4)

SYMBOL	PARAMETER	CONDITIONS	TYP.	UNIT
V _{P2}	supply voltage		23	V
I _P	supply current		215	mA
V ₇	DC output voltage		11.8	V
V _{7M}	peak output voltage		45	V
l ₇	output current		0.8	A
I _{Y(p-p)}	vertical deflection current (peak-to-peak value)		1.5	A
t _{fb}	flyback time		0.3	ms
t _{bl}	blanking pulse duration		1.25	ms
P _{tot}	total power dissipation		3.3	W
f _o	free running oscillator frequency	without sync	45	Hz

PACKAGE OUTLINE



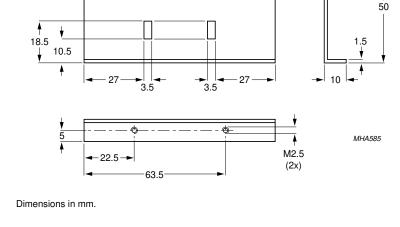
TDA4800

1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

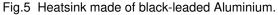
OUTLINE	REFERENCES			EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	EIAJ		PROJECTION	ISSUE DATE
SOT141-6					$\blacksquare $	-92-11-17- 95-03-11

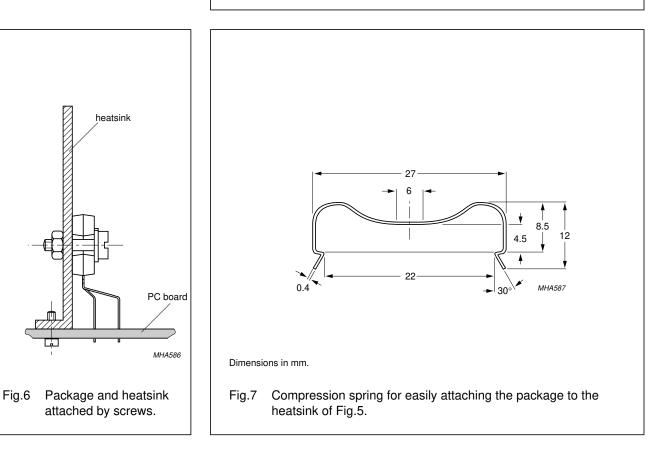
MOUNTING INSTRUCTIONS FOR 13-LEAD DBS13P POWER PACKAGE

The rise in temperature caused by power dissipation in the circuit is reduced by adding a heatsink with a sufficiently low thermal resistance: $R_{th(mb-h)} + R_{th(h-a)} = R_{th(mb-a)}$ (e.g. the heatsink of Fig.5). It is possible to attach the package to the heatsink by screws (Fig.6) or by a compression spring (Fig.7). A layer of silicon grease between the heatsink and the mounting base optimizes thermal contact.



86





Product specification

SOLDERING

Introduction

There is no soldering method that is ideal for all IC packages. Wave soldering is often preferred when through-hole and surface mounted components are mixed on one printed-circuit board. However, wave soldering is not always suitable for surface mounted ICs, or for printed-circuits with high population densities. In these situations reflow soldering is often used.

This text gives a very brief insight to a complex technology. A more in-depth account of soldering ICs can be found in our *"IC Package Databook"* (order code 9398 652 90011).

Soldering by dipping or by wave

The maximum permissible temperature of the solder is 260 $^{\circ}$ C; solder at this temperature must not be in contact with the joint for more than 5 seconds. The total contact time of successive solder waves must not exceed 5 seconds.

The device may be mounted up to the seating plane, but the temperature of the plastic body must not exceed the specified maximum storage temperature ($T_{stg max}$). If the printed-circuit board has been pre-heated, forced cooling may be necessary immediately after soldering to keep the temperature within the permissible limit.

Repairing soldered joints

Apply a low voltage soldering iron (less than 24 V) to the lead(s) of the package, below the seating plane or not more than 2 mm above it. If the temperature of the soldering iron bit is less than $300 \,^{\circ}$ C it may remain in contact for up to 10 seconds. If the bit temperature is between 300 and 400 $^{\circ}$ C, contact may be up to 5 seconds.

DEFINITIONS

Data sheet status Objective specification This data sheet contains target or goal specifications for product development. Preliminary specification This data sheet contains preliminary data; supplementary data may be published later. Product specification This data sheet contains final product specifications. Limiting values Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

Application information

Where application information is given, it is advisory and does not form part of the specification.

LIFE SUPPORT APPLICATIONS

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TDA4800

NOTES

14

TDA4800

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